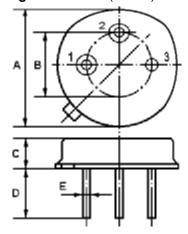


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The ACTQ868.3D/868.3/TO39 is a two-port, 180° surface-acoustic-wave (SAW) resonator in a low-profile metal TO-39 case. It provides reliable, fundamental-mode, quartz frequency stabilization i.e. in transmitters or local oscillators operating at 868.300 MHz.

1.Package Dimension (TO-39)

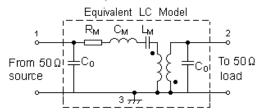


2.

Pin	Configuration			
1	Input / Output			
2	Output / Input			
3	Case Ground			

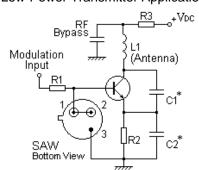
Dimension	Data (unit: mm)		
А	9.30±0.20		
В	5.08±0.10		
С	3.40±0.20		
D	3±0.20 / 5±0.20		
Е	0.45±0.20		

3. Equivalent LC Model and Test Circuit

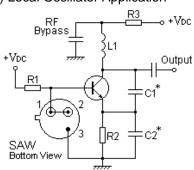


4.Typical Application Circuits

1) Low-Power Transmitter Application



2) Local Oscillator Application



Issue: 1 C1

Date: SEPT 04

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

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For quotations or further information please contact us at:

3 The Business Centre, Molly Millars Lane, Wokingham, Berks, RG41 2EY, UK

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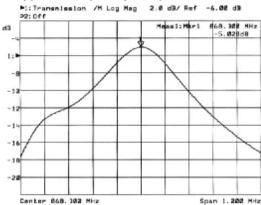


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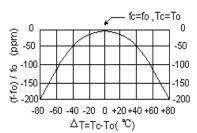
Issue: 1 C1

Date: SEPT 04

5. Typical Frequency Response



6.Temperature Characteristics



The curve shown above accounts for resonator contribution only and does not include LC component temperature characteristics.

7.Performance

7-1.Maximum Ratings

Rating	Value	Unit	
CW RF Power Dissipation	Р	10	dBm
DC Voltage Between Any Two Pins	V_{DC}	±30	V
Storage Temperature Range	$T_{\rm stg}$	-40 to +85	°C
Operating Temperature Range	T _A	-10 to +60	°C

7-2. Electronic Characteristics

7 Z.Electionic Orlandicionatics										
	Characteristic	Sym	Minimum	Typical	Maximum	Unit				
Centre Frequency (+25°C)	Absolute Frequency	fc	868.150		868.450	MHz				
	Tolerance from 868.300 MHz	Δf_{C}		±150		kHz				
Insertion Loss		IL		6.0	8.0	dB				
Quality Factor	Unloaded Q	Q _U		5,400						
	50 Ω Loaded Q	Q_L		2,700						
Temperature Stability	Turnover Temperature	To	25		55	°C				
	Turnover Frequency	f _O		fc		kHz				
	Frequency Temperature Coefficient	FTC		0.032		ppm/°C				
Frequency Aging Absolute Value during the First Year		f _A		≤10		ppm/yr				
DC Insulation Resistance Between Any Two Pins			1.0			МΩ				
RF Equivalent RLC Model	Motional Resistance	R_{M}		99.5	151	Ω				
	Motional Inductance	L _M		98.7819		μН				
	Motional Capacitance	См		0.3405		fF				
	Shunt Static Capacitance	Со	2.20	2.50	2.80	pF				

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1 CAUTION: Electrostatic Sensitive Device. Observe precautions for handling!

- 1. The frequency f_C is the frequency of minimum IL with the resonator in the specified test fixture in a 50 Ω test system with VSWR ≤ 1.2:1. Typically, foscillator or ftransmitter is less than the resonator fc.
- 2. Unless noted otherwise, case temperature $T_C = +25^{\circ}C \pm 2^{\circ}C$.
- Frequency aging is the change in f_C with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- 4. Turnover temperature, T₀, is the temperature of maximum (or turnover) frequency, f₀. The nominal frequency at any case temperature, T_C , may be calculated from: $f = f_0 [1 - FTC (T_0 - T_C)^2]$. Typically, oscillator T_0 is 20° less than the specified resonator T_0 .
- This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C₀ is the measured static (non-motional) capacitance between either Pin 1 and ground or Pin 2 and ground. The measurement includes case parasitic capacitance.
- 6. Derived mathematically from one or more of the following directly measured parameters: f c, IL, 3 dB bandwidth, f_C versus T_C, and C₀.
- 7. The specifications of this device are based on the test circuit shown above and subject to change or obsolescence without notice.
- 8. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 9. Our liability is only assumed for the Surface Acoustic Wave (SAW) component(s) per se, not for applications, processes and circuits implemented within components or assemblies.

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